# UN2211/2212/2213/2214/2215/2216/2217/2218/2219/2210/ 221D/221E/221F/221K/221L/221M/221N/221T/221V/221Z

# Silicon NPN epitaxial planer transistor

### For digital circuits

### Features

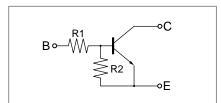
- Costs can be reduced through downsizing of the equipment and reduction of the number of parts.
- Mini type package, allowing downsizing of the equipment and automatic insertion through tape packing and magazine packing.

### Resistance by Part Number

	Marking Symbol	$(R_1)$	$(R_2)$
• UN2211	8A	$10k\Omega$	$10k\Omega$
• UN2212	8B	$22k\Omega$	$22k\Omega$
• UN2213	8C	$47 \mathrm{k}\Omega$	$47 \mathrm{k}\Omega$
• UN2214	8D	$10k\Omega$	$47 \mathrm{k}\Omega$
• UN2215	8E	$10k\Omega$	_
• UN2216	8F	$4.7 \mathrm{k}\Omega$	_
• UN2217	8H	$22k\Omega$	_
• UN2218	8I	$0.51 \mathrm{k}\Omega$	$5.1 \mathrm{k}\Omega$
• UN2219	8K	$1k\Omega$	$10k\Omega$
• UN2210	8L	$47 \mathrm{k}\Omega$	_
• UN221D	8M	$47 \mathrm{k}\Omega$	$10k\Omega$
• UN221E	8N	$47 \mathrm{k}\Omega$	$22k\Omega$
• UN221F	8O	$4.7 \mathrm{k}\Omega$	$10k\Omega$
• UN221K	8P	$10k\Omega$	$4.7 \mathrm{k}\Omega$
• UN221L	8Q	$4.7 \mathrm{k}\Omega$	$4.7 \mathrm{k}\Omega$
• UN221M	EL	$2.2k\Omega$	$47 \mathrm{k}\Omega$
• UN221N	EX	$4.7 \mathrm{k}\Omega$	$47 \mathrm{k}\Omega$
• UN221T	EZ	$22k\Omega$	$47 \mathrm{k}\Omega$
• UN221V	FD	$2.2 k\Omega$	$2.2k\Omega$
• UN221Z	FF	$4.7 \mathrm{k}\Omega$	$22k\Omega$

# Unit: mm 2.8 -0.2 2.8 -0.3 0.65±0.15 1.5 -0.05 0.65±0.15 0.65±0.15 1.5 -0.05 0.65±0.15 1.5 -0.05 0.65±0.15 1.5 -0.05 0.65±0.15 0.6

### Internal Connection



### Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol Ratings		Unit	
Collector to base voltage	$V_{CBO}$	50	V	
Collector to emitter voltage	V <sub>CEO</sub>	50	V	
Collector current	$I_C$	100	mA	
Total power dissipation	$P_{T}$	200	mW	
Junction temperature	$T_{j}$	150	°C	
Storage temperature	$T_{stg}$	-55 to +150	°C	

# Transistors with built-in Resistor 221D/221E/221F/221K/221L/221M/221N/221T/221V/221Z

# Electrical Characteristics (Ta=25°C)

Parameter		Symbol	Conditions	min	typ	max	Unit	
Collector cutoff current		$I_{CBO}$	$V_{CB} = 50V, I_E = 0$			0.1	μА	
		I <sub>CEO</sub>	$V_{CE} = 50V, I_{B} = 0$			0.5	μA	
UN221	UN2211	UN2211		$V_{EB} = 6V$ , $I_C = 0$			0.5	mA
	UN2212/2214/221E/221D/221M/221N/221T UN2213 UN2215/2216/2217/2210 UN221F/221K		I <sub>EBO</sub>				0.2	
							0.1	
Emitter							0.01	
cutoff current							1.0	
	UN2219	UN2219					1.5	
	UN2218/221L/2	221V					2.0	-
	UN221Z						0.4	
Collecto	r to base voltage		V <sub>CBO</sub>	$I_{\rm C} = 10 \mu A, I_{\rm E} = 0$	50			V
Collecto	r to emitter voltag	e	V <sub>CEO</sub>	$I_C = 2mA$ , $I_B = 0$	50			V
	UN2211				35			
	UN2212/221E				60			
Forward	UN2213/2214/2	221M			80			
current	UN2215*/2216*/	N2215*/2216*/2217*/2210*		V 10V 7 5 1	160		460	
transfer	UN221F/221D/	2219	h <sub>FE</sub>	$V_{CE} = 10V, I_C = 5mA$	30			
ratio	UN2218/221K/	18/221K/221L			20			
	UN221N/221T				80		400	_
	UN221V				60		200	
Collecto	r to emitter satura	tion voltage	V	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0.3 {\rm mA}$			0.25	V
UN221V		V <sub>CE(sat)</sub>	$I_C = 10 \text{mA}, I_B = 1.5 \text{mA}$		0.04	0.25		
Output v	Output voltage high level		V <sub>OH</sub>	$V_{CC} = 5V, V_B = 0.5V, R_L = 1k\Omega$	4.9			V
Output v	Output voltage low level			$V_{CC} = 5V, V_B = 2.5V, R_L = 1k\Omega$			0.2	
UN2213/221K UN221D UN221E		V <sub>OL</sub>	$V_{CC} = 5V, V_B = 3.5V, R_L = 1k\Omega$			0.2	V	
			$V_{CC} = 5V, V_B = 10V, R_L = 1k\Omega$			0.2		
			$V_{CC} = 5V, V_B = 6V, R_L = 1k\Omega$			0.2		
Transition frequency		$f_T$	$V_{CB} = 10V$ , $I_E = -2mA$ , $f = 200MHz$		150		MHz	
Input resistance	UN2211/2214/2215/221K		R <sub>1</sub>			10		
	UN2212/2217/221T					22		
	UN2213/221D/221E/2210					47		
	UN2216/221F/221L/221N/221Z				(-30%)	4.7	(+30%)	$k\Omega$
	UN2218					0.51		
	UN2219					1		
	UN221M/221V					2.2		

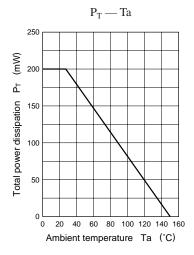
## \* h<sub>FE</sub> rank classification (UN2215/2216/2217/2210)

Rank	Q	R	S
$h_{FE}$	160 to 260	210 to 340	290 to 460

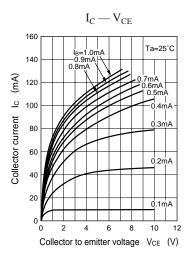
# ■ Electrical Characteristics (continued) (Ta=25°C)

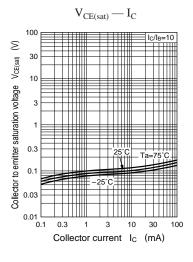
	Parameter	Symbol	Conditions	min	typ	max	Unit
Resistance ratio	UN2211/2212/2213/221L			0.8	1.0	1.2	
	UN2214			0.17	0.21	0.25	
	UN2218/2219	-		0.08	0.1	0.12	
	UN221D				4.7		
	UN221E				2.14		
	UN221F/221T	$R_1/R_2$			0.47		
	UN221K				2.13		
	UN221M				0.047		
	UN211N				0.1		
	UN211V				1.0		
	UN211Z				0.21		

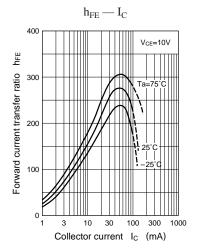
### Common characteristics chart

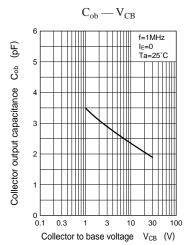


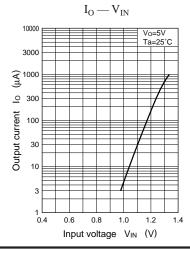
### Characteristics charts of UN2211

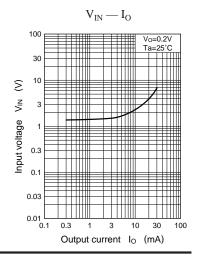


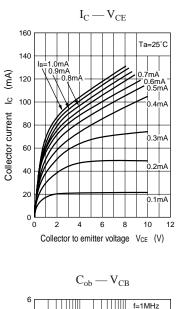


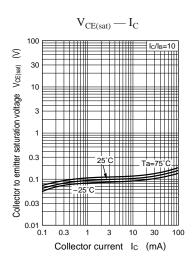


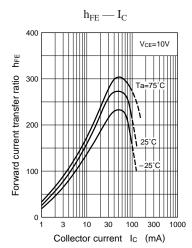


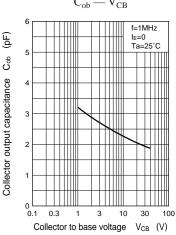


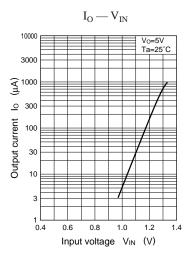


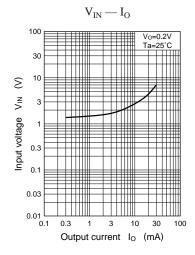




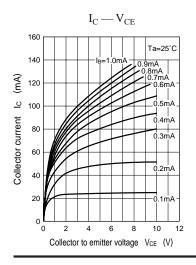


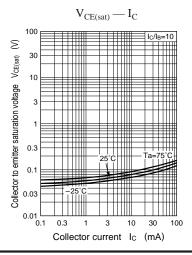


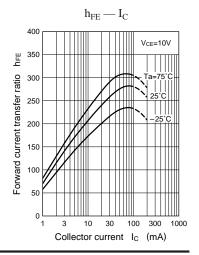


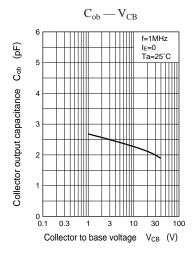


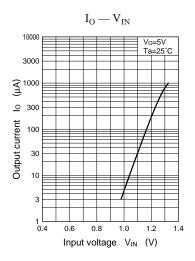
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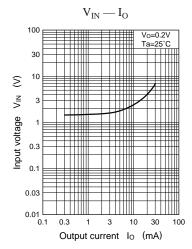


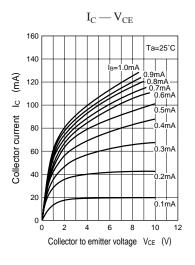


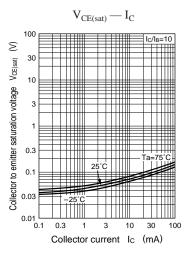


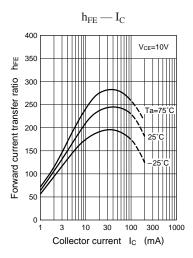


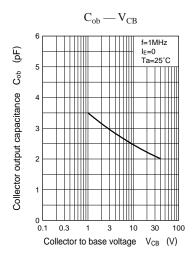


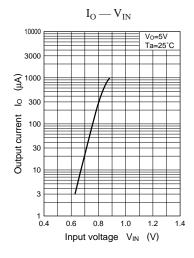


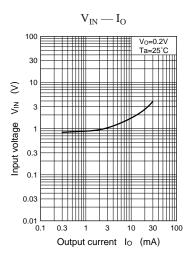






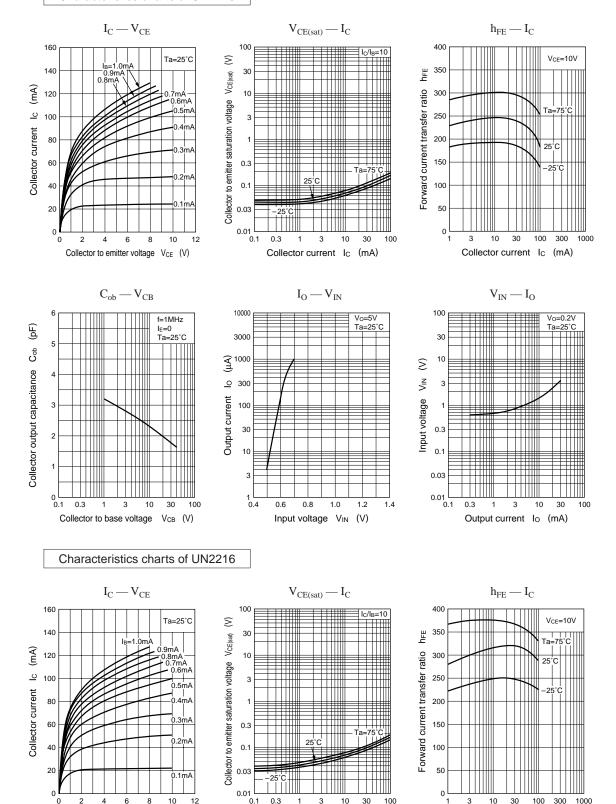






4 6 8 10

Collector to emitter voltage VCE (V)



0.3

Collector current I<sub>C</sub>

7 **Panasonic** 

30

Collector current I<sub>C</sub> (mA)

10

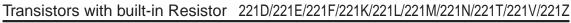
300 1000

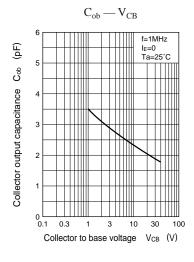
100

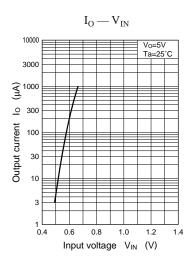
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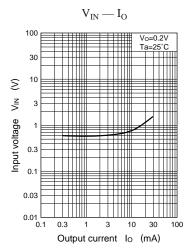
(mA)

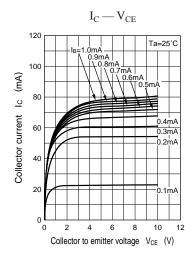
10

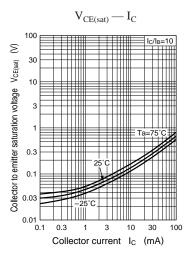


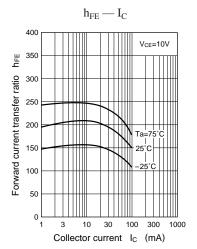


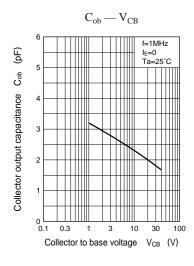


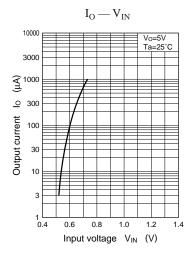


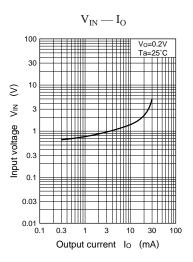


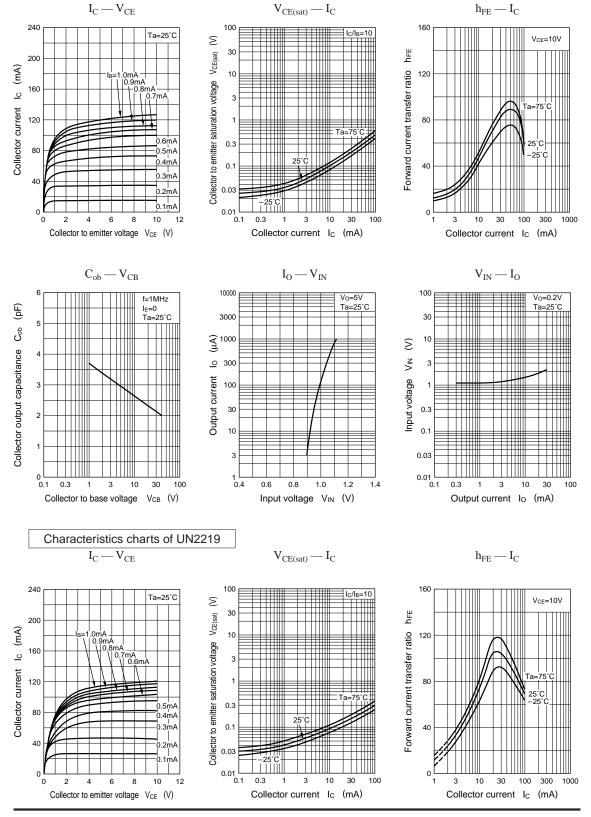


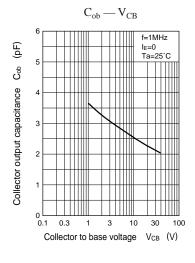


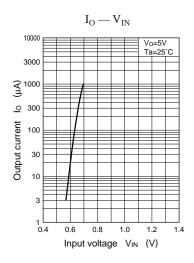


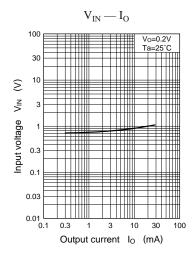


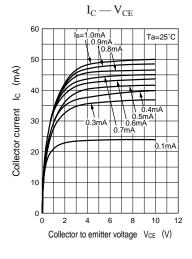


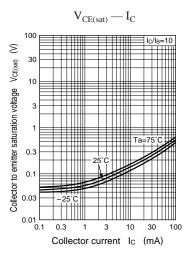


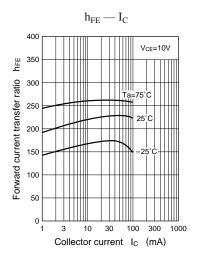


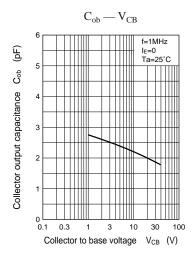


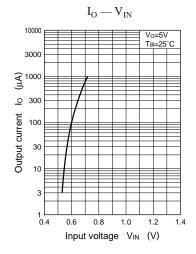


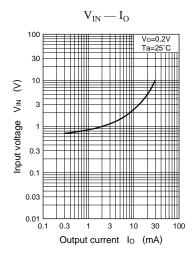


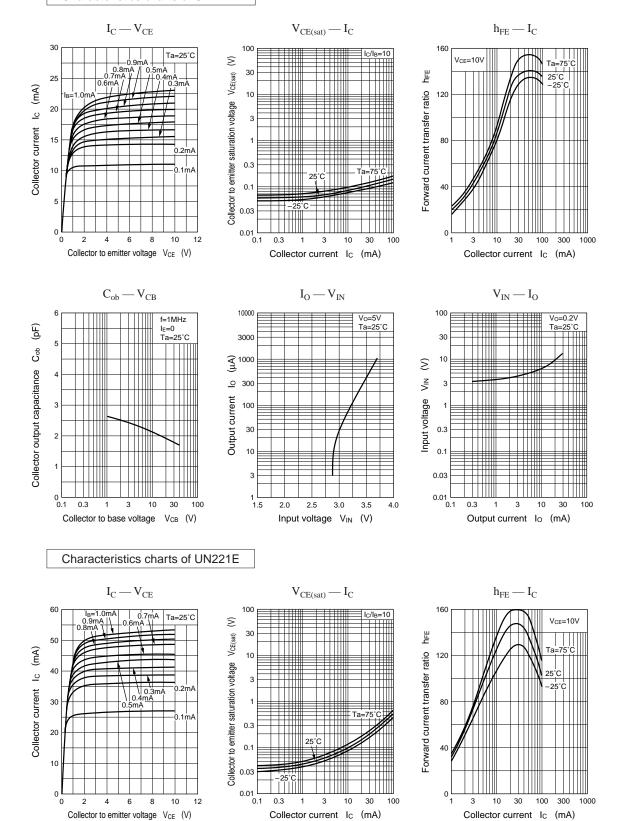


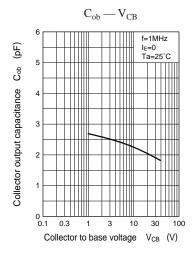


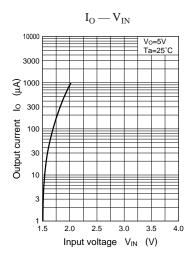


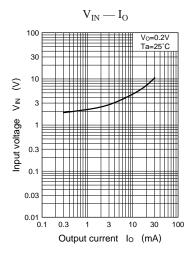


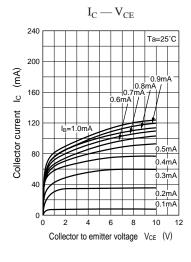


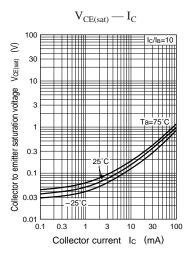


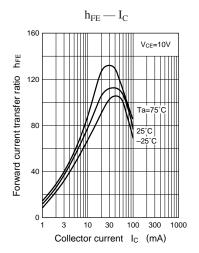


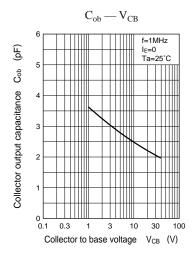


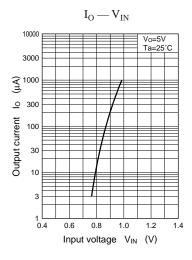


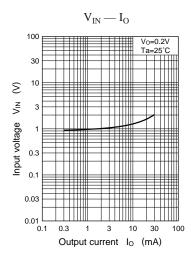


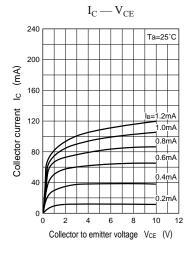


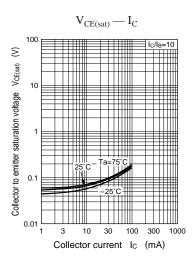


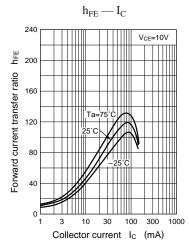


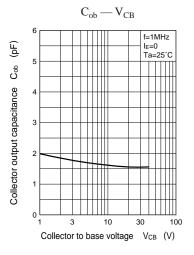


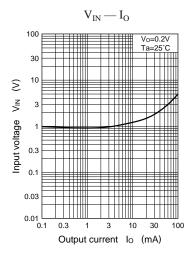












### Characteristics charts of UN221L

